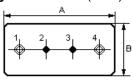


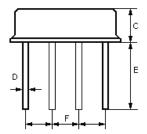
Tel: +44 118 979 1238 Fax: +44 118 979 1283

Email: info@actcrystals.com

The ACTQ434/433.92/F11 is a two-port, 180° surface-acoustic-wave (SAW) resonator in a low-profile metal F-11 case. It provides reliable, fundamental-mode, quartz frequency stabilization i.e. in transmitters or local oscillators operating at 433.920 MHz.

1.Package Dimension (F-11)



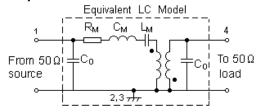


2.

Pin	Configuration		
1,4	Input / Output		
2/3	Case Ground		

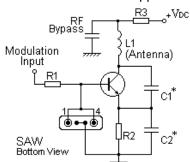
Dimension	ension Data (unit: mm)			
А	11.0±0.3			
В	4.5±0.3			
С	3.2±0.3			
D	0.45±0.1			
Е	5.0±0.5			
F	2.54±0.2			

3. Equivalent LC Model and Test Circuit

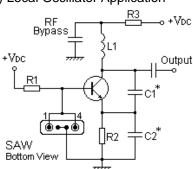


4. Typical Application Circuits

1) Low-Power Transmitter Application



2) Local Oscillator Application



Issue: 1 C1

Date: SEPT 04

In keeping with our ongoing policy of product evolvement and improvement, the above specification is subject to change without notice.

ISO9001: 2000 Registered - Registration number 6830/2

For quotations or further information please contact us at:

3 The Business Centre, Molly Millars Lane, Wokingham, Berks, RG41 2EY, UK

http://www.actcrystals.com



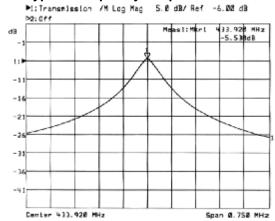
Tel: +44 118 979 1238 Fax: +44 118 979 1283

Issue: 1 C1

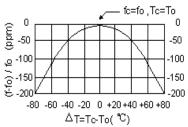
Date: SEPT 04

Email: info@actcrystals.com

5. Typical Frequency Response



6.Temperature Characteristics



The curve shown above accounts for resonator contribution only and does not include LC component temperature characteristics.

7.Performance

7-1.Maximum Ratings

Rating	Value	Units	
CW RF Power Dissipation	10	dBm	
DC Voltage Between Any Two Pins	±30V	VDC	
Case Temperature	-40 to +85	°C	

7-2. Electronic Characteristics

7 Z.Electronic Onaracteristics									
	Characteristic	Sym	Minimum	Typical	Maximum	Units			
Centre Frequency (+25 °C)	Absolute Frequency	f _C	433.845		433.995	MHz			
	Tolerance from 433.920MHz	Δf_{C}		±75		kHz			
Insertion Loss		IL		6.0	8.0	dB			
Quality Factor	Unloaded Q	Q _U		13,450					
	50 Ω Loaded Q	Q_L		6,700					
Temperature Stability	Turnover Temperature	T ₀	25		55	°C			
	Turnover Frequency	f ₀		fc		kHz			
	Frequency Temperature Coefficient	FTC		0.03		ppm/°C ²			
Frequency Aging	Absolute Value during the First Year	f _A		≤10		ppm/yr			
DC Insulation Resistance Between Any Two Pins			1.0			ΜΩ			
RF Equivalent RLC Model	Motional Resistance	R _M		99.5	151	Ω			
	Motional Inductance	L _M		490.5106		μН			
	Motional Capacitance	См		0.27454		fF			
	Shunt Static Capacitance	C ₀	1.4	1.7	2.0	pF			

i CAUTION: Electrostatic Sensitive Device. Observe precautions for handling!

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- 1. The frequency f_C is the frequency of minimum IL with the resonator in the specified test fixture in a 50 Ω test system with VSWR ≤ 1.2:1. Typically, foscillator or ftransmitter is less than the resonator fc.
- 2. Unless noted otherwise, case temperature $T_C = +25^{\circ}C \pm 2^{\circ}C$.
- 3. Frequency aging is the change in fc with time and is specified at +65°C or less. Aging may exceed the specification for prolonged temperatures above +65°C. Typically, aging is greatest the first year after manufacture, decreasing in subsequent years.
- Turnover temperature, T_0 , is the temperature of maximum (or turnover) frequency, f_0 . The nominal frequency at any case temperature, T_C , may be calculated from: $f = f_0 [1 - FTC (T_0 - T_C)^2]$. Typically, oscillator T_0 is 20° less than the specified resonator T_0 .
- This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only. The capacitance C_0 is the measured static (non-motional) capacitance between either Pin 1 and ground or Pin 4 and ground. The measurement includes case parasitic capacitance.
- 6. Derived mathematically from one or more of the following directly measured parameters: f c, IL, 3 dB bandwidth, f_C versus T_C , and C_0 .
- 7. The specifications of this device are based on the test circuit shown above and subject to change or obsolescence without notice.
- Typically, equipment utilizing this device requires emissions testing and government approval, which is the responsibility of the equipment manufacturer.
- 9. Our liability is only assumed for the Surface Acoustic Wave (SAW) component(s) per se, not for applications, processes and circuits implemented within components or assemblies.

In keeping with our ongoing policy of product evolvement and improvement, the above specification is subject to change without notice.